

FIG. 5

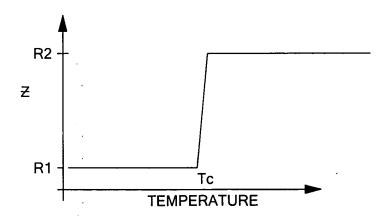
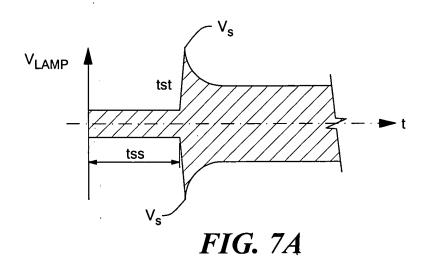
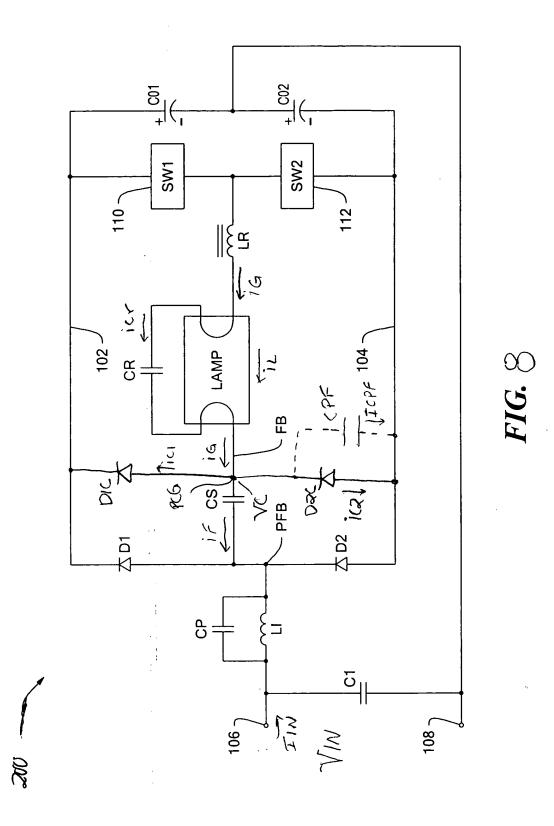


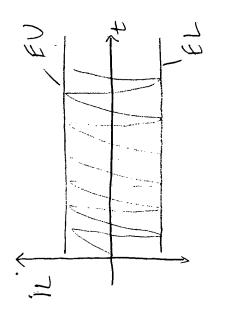
FIG. 6

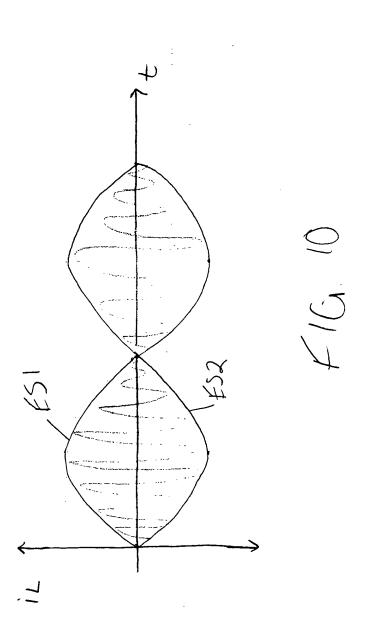


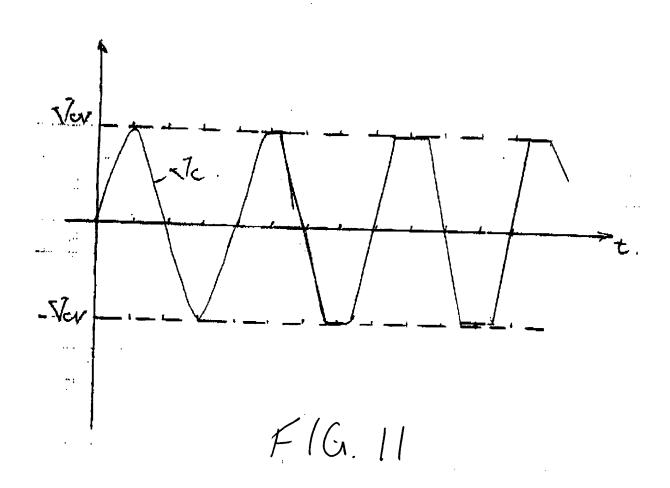
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FIG. 7B

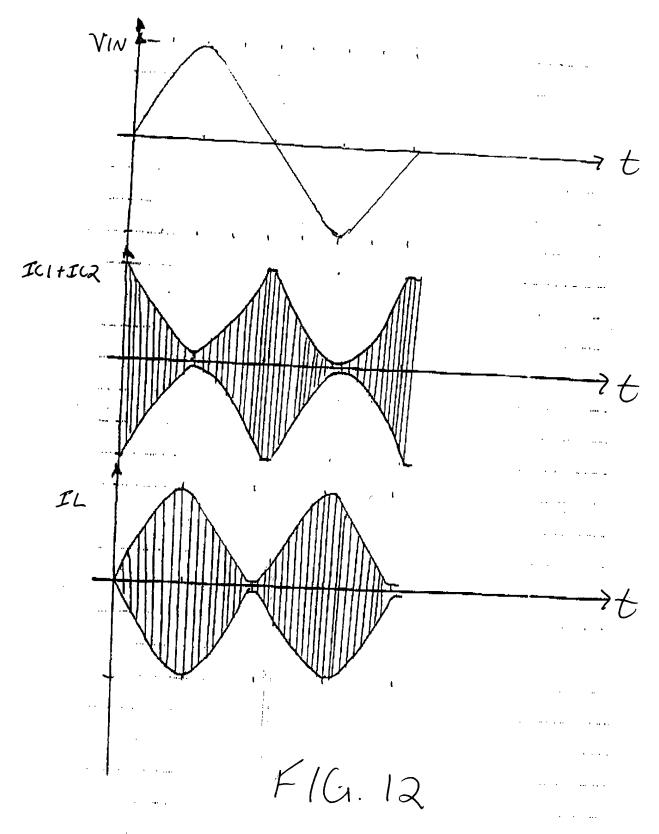






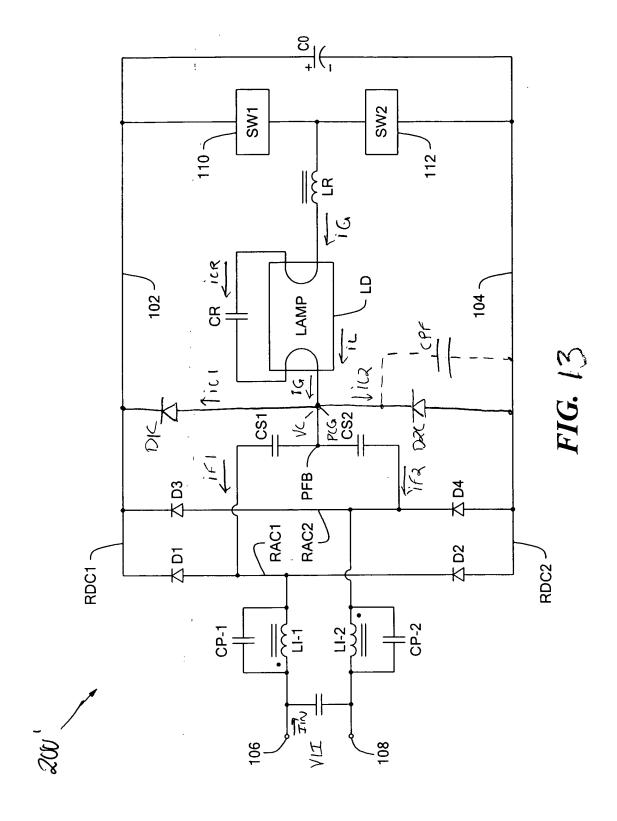


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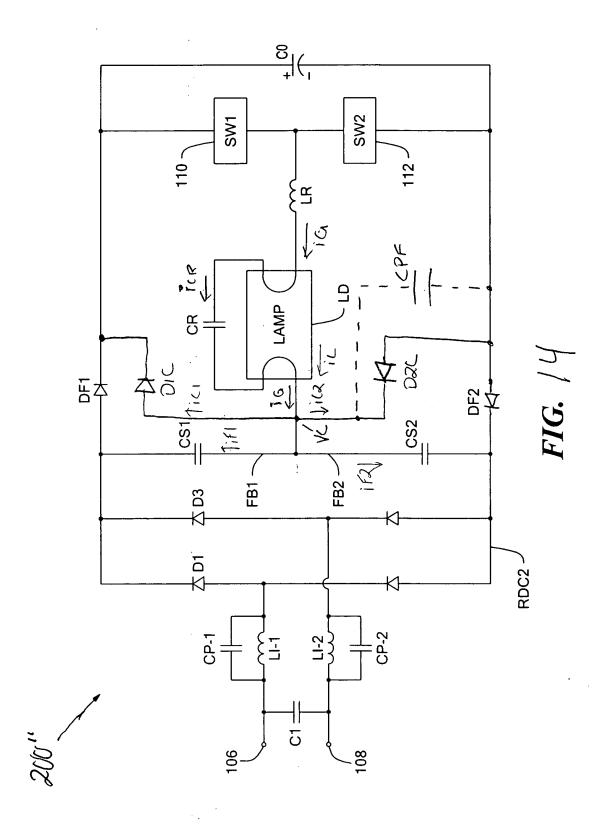


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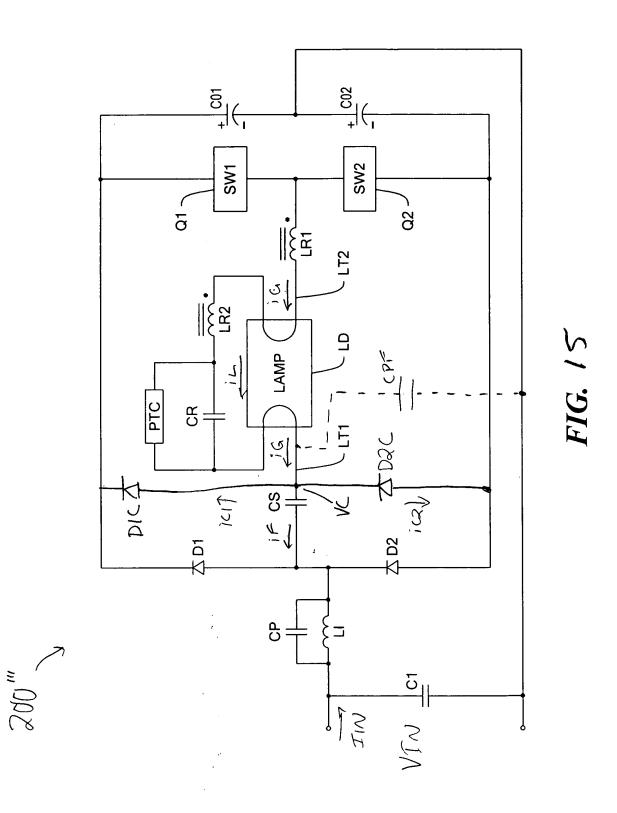
12/19



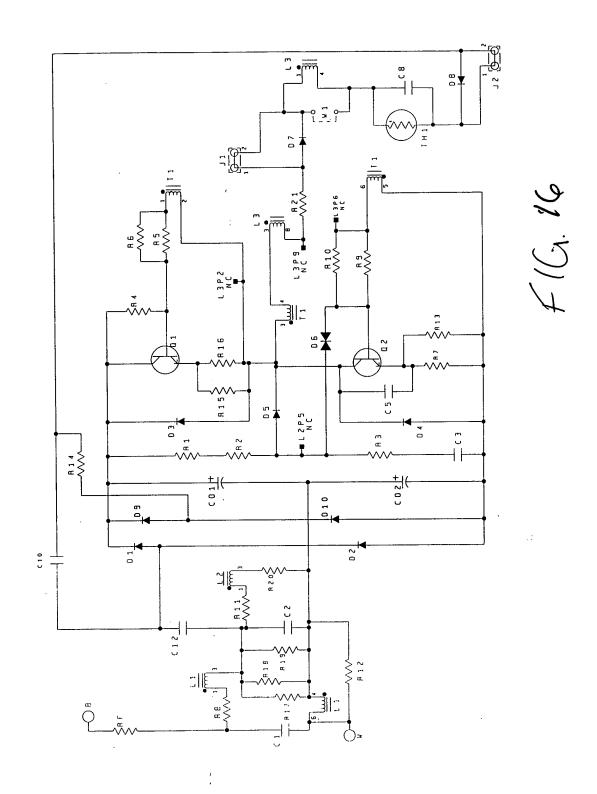
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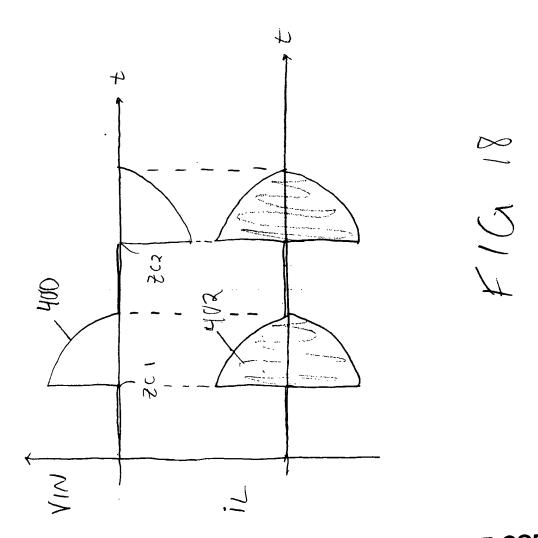


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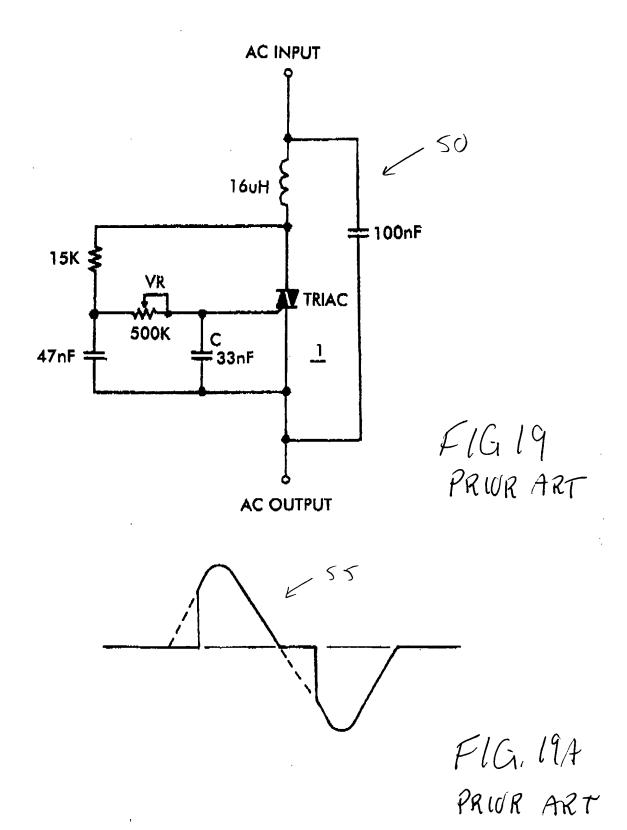


9%), AL=100

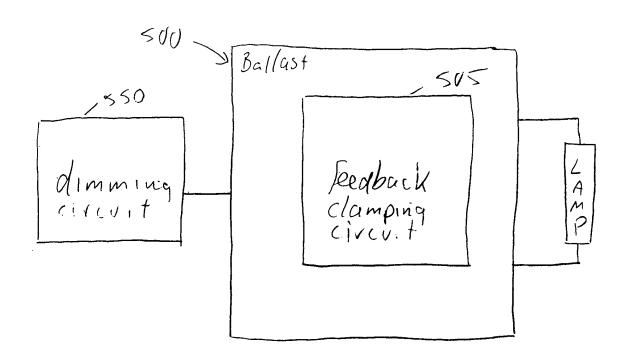
REF. DESIGN.	DESCRIPTION
L3	Inductor Assy, 1.69mH (+/-3%), AL=100
	130T/10T, 3x33AWG Litz, 7pin, CS-L3
L2	Inductor Assy, 1.90mH, AL=65
	171T, 29AWGH, 5pin, CS-L2
L1	Inductor Assy, 1.90mH, AL=65
	171T, 29AWGH, 5pin, CS-L2
T1	Torroid Transformer, CSI
	H40-T(9x4x5) (1-1-5)T
C3	Capacitor, Ceramic, SMD,
	0.1uF, 50Vdc, 10%, 1206 Pkg.
C1	Capacitor, Metallized Polyester, 5mm
	0.01uF, 400Vdc, 10%
C2	Capacitor, Metallized Polyester, 5mm
	Epoxy-Dipped, 33nF, 250Vdc, 10%
C12	Capacitor, Plypropylene, 5mm
	Epoxy-Dipepd, 2.7nF, 400Vdc, 10%
C5	Capacitor, Ceramic, Radial
	100pF, 1000Vdc, 5 mm
C8 .	
	Capacitor, Polypropylene. 5mm
C10	Epoxy-Dipped, 2.2nF, 1500V,10%
	Capcitor, Polypropylene, 5mm
CO1,CO2	Epoxy-Dipped, 4.7nF, 400Vdc, 10%
001,002	Capacitor, Electrolytic, (10x20)mm
D5	33uF, 200Vdc, 105C, 5mm
	Diode, Axial, Glass-Passivated
D1-D4, D9-D10	Fast, 1000V, 1N4007GP
	Diode, Axial, Glass-Passivated
D6	Ultra-Fast, 1000V, UF4007GP
RF	Diac, Axial, 32V Db 3
NF	Fuse, Axial
R7, R15	3A/250V
K/, K/3	Resistor, SMD, 1206 Pkg,
R8, R11, R12,	0 Ohm
R14, R20, R21	Resistor, SMD, 1206 Fkg,
R6, R10, R13, R16	0 Ohm
NOT USED	Resistor, SMD, 1206 Pkg,
R3	
K3	Resistor, SMD,1206 Pkg,
D5 D0	33 Ohm, 5%, 1/4W
R5, R9,	Resistor, SMD,1206 Pkg,
D4 D0	20 Ohm, 1%, 1/4W
R1,R2	Resistor, SMD,1206 Fkg,
<u> </u>	150 kOhm, 5%, 1/4W
R4	Resistor, SMD,1206 Pkg,
D/7 D/A	300 kOhm, 5%, 1/4\V
R17-R19	Resistor, SMD, 1206 Pkg,
NOT USED	
Q1,Q2	Transistor Power,TO-220
	ST13005
J1, J1	Terminal, Radial,
Westerness and the second of t	2 pin, CSI
TH1	Thermistor, PTC
NOT USED	



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